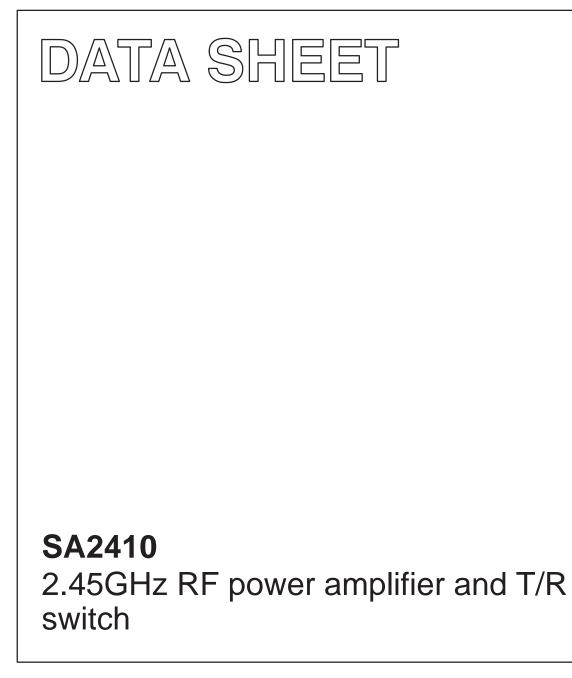
INTEGRATED CIRCUITS



Preliminary specification

1997 Sept 09

IC17 Data Handbook





DESCRIPTION

The SA2410 is a GaAs monolithic power amplifier with an integrated T/R switch designed to meet requirements for 802.11 (WLAN). The SA2410 uses an on-chip 4 GHz oscillator to generate the negative bias, thus eliminating the need for a negative supply. It operates from 3V to 5.5V and consumes 125 mA with an output power of 18.5 dB (typ). It is suitable for other 2.45 GHz ISM band applications.

FEATURES

- V_{CC}=3V-5.5V
- No negative bias needed
- I_{CC}=125mA (typ) @ 3.3V
- P_{OUT}=18.5 dB(typ)
 IM3<-30dBc
 IM5<-50dBc
- Gain=29dB (typ)
- Attenuation range=16dB (typ)
- LQFP-32 package

APPLICATIONS

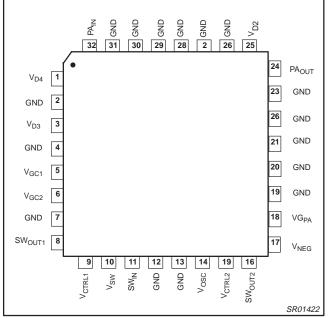
- 802.11 WLAN
- 2.4-2.5 GHz ISM BAND

ORDERING INFORMATION

DESCRIPTION			TEMPERATURE RANGE		ORDER CODE	DWG #
2–Pin Plastic Thin Quad Flat Package			−40° C+85°C		SA2410	SOT401-1
ENERAL SP	PECIFICATIONS					
Symbol	Parameter	Condition	Min	Тур	Max	Unit
Т	Temperature		-40		+85	С
V _{CC}	Supply V		3		5.5	V
I _{CC}	Supply I	3.3 volts		125		mA
Power Amplifier						
f _{RF}	Frequency Range		2.4		2.5	GHz
IM3	IM3 2 tones		30			dBc
IM5	IM5 2 tones		50			dBc
T _{on}	Transmit power on	Including neg. supply			2	μs
T _{off}	Xmit power down				2	μs
Gain	Small signal gain			29		dB
P _{out}	Output power	IM3=30dBc IM5=50dBc 125mA@3.3 volts	17.5	18.5		dBm
Eff.	Efficiency			25		%
Δ Gt1	Gain variation with temp	–40 to +85°C		± 3.5	5	dB
Δ Gt2	Gain variation with temp	0–70°C		±2.0)	dB
Δ Gr	Ripple	2.45±0.05 GHz	1	±1		dB
Δ Gvd	Gain variation with supply	3.3 volts ± 0.3 V	İ	0.5		dB

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Symbol	Parameter	Condition	Min	Тур	Max	Unit
Negative voltage	supply				-	
t _{on}	Power on time		10		100	nS
	4 GHz spur	Xmit Mode		TBD		dBm
Linear Gain Con	trol				-	
Symbol	Parameter	Condition	Min	Тур	Max	Unit
V _{GC}	Gain control voltage			TBD		Volt
C _{GC}	Input C at gain pin			TBD		pF
G _{CR}	Attenuation range			16		dB
Transmit/receive	switch				-	
Symbol	Parameter	Condition	Min	Тур	Max	Unit
L _{tx}	Insertion loss T _x			1.3	2	dB
L _{rx}	Insertion loss R _x			1.3	2	dB
t _{sw}	Switch response time				400	nS
ISO _{PA}	Isolation switch to PA		30			dB
Z _{in}	Input impedance			50		Ω
Z _{out}	Output impedance			50		Ω
ISO _{SW}	Switch Isolation		17	19		dB

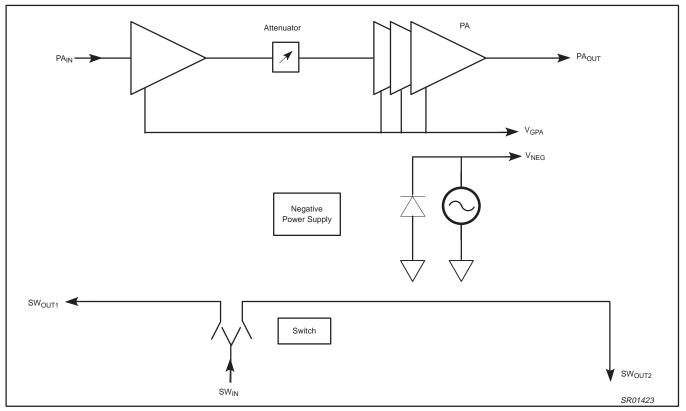
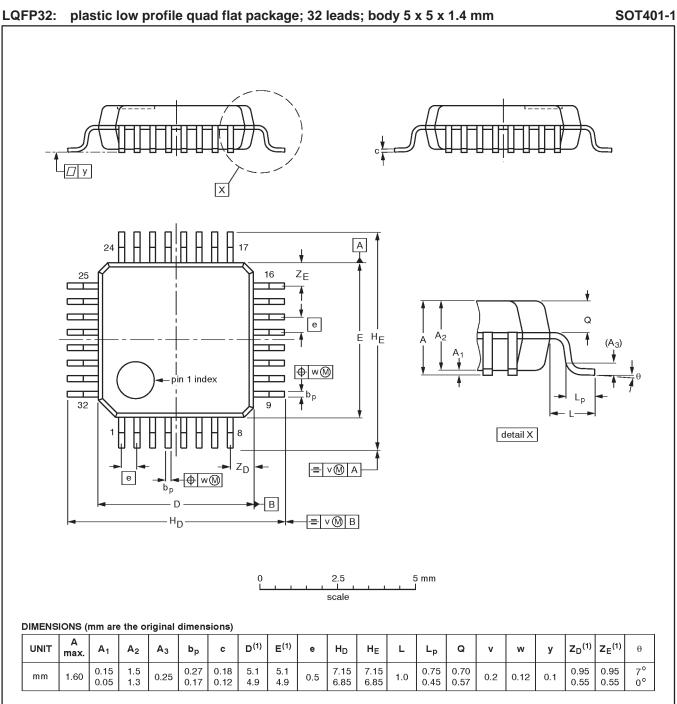


Figure 2. Block Diagram

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Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN	ISSUE DATE	
	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT401-1						94-04-25 95-12-19	

SA2410

Preliminary specification

2.45GHz RF power amplifier and T/R switch

SA2410

NOTES

SA2410

DEFINITIONS				
Data Sheet Identification	Product Status	Definition		
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.		
Preliminary Specification	Preproduction Product	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.		
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